



Laser Diode LT-LD-520-1W-P

LT-LD-520-1W-P is a multimode laser diode with 1W CW output power at 520nm. It is supplied in a 9mm floating mounted TO. The laser diode is suitable for the use in various opto-electronic applications.

■ Absolute Maximum Ratings (T_c=25°C)

Parameter	Symbol	Value	Unit
Optical Current (CW)	I _{op}	1.8	A
Optical Power Output (CW)	P _o	1.2	W
Reverse Voltage	V _{rl}	2	V
Operating Case Temperature	T _c	0~+60	°C
Storage Temperature	T _{stg}	-40~+85	°C
Soldering temperature	T _{slid}	350	°C

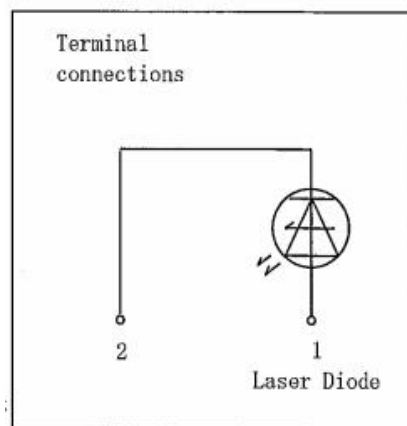
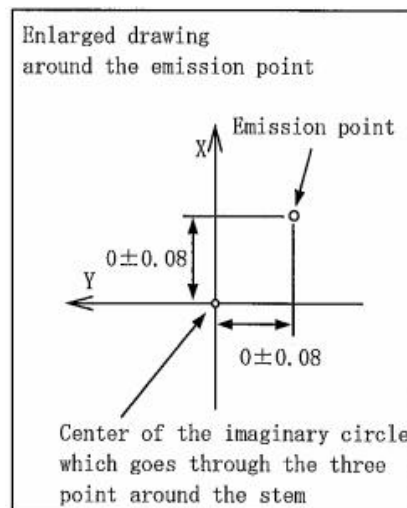
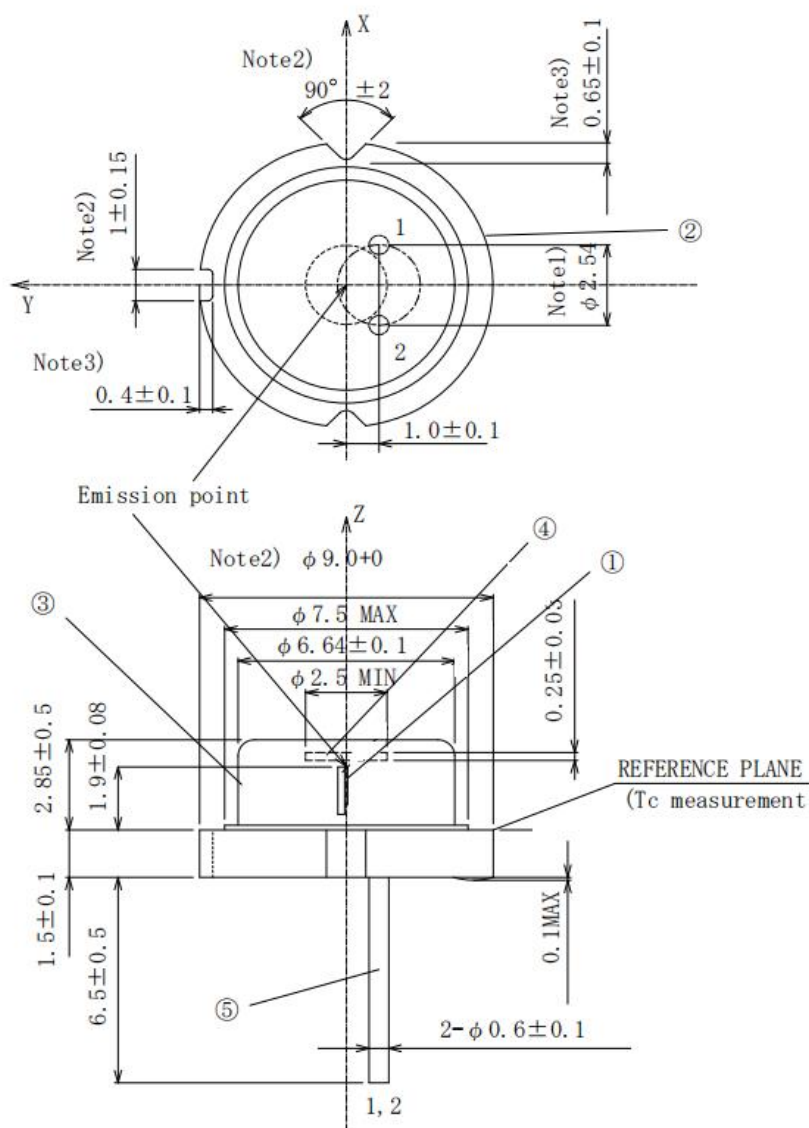
■ Initial Electrical/Optical Characteristics (T_c=25°C)

Parameter	Symbol	Condition	Min	Typ.	Max	Unit
Threshold Current	I _{th}	-	-	0.18	0.30	A
Operating Current	I _{op}	P _o =1W	-	1.4	1.79	A
Operating Voltage	V _{op}		-	5.4	6.5	V
Dominant Wavelength	λ _d		510	(520)	530	nm
Beam Divergence *	Parallel		5	9	20	°
	Perpendicular		35	44	55	°
Differential Efficiency	η _d		0.45	0.8	-	W/A

() are reference figures.

* Full angle at 1/e² from peak intensity

■ Outline Dimension (Unit:mm)



Note 1) Dimension of the bottom of leads.

Note 2) These dimensions are valid only in the range of 0~0.75mm below from the reference plane.

Note 3) These dimensions are defined from the imaginary circle which goes through the three points around the stem to the bottom of cut off parts.

■ Cautions

1. Laser light can damage the human eye and skin. Do not expose the eye and skin to any laser light directly or through optical lenses. Focused laser beam through optical instruments will increase the chance of eye hazard.
2. The laser needs a stable driver to avoid surges. The instantaneous reverse current and reverse voltage should not exceed the absolute maximum ratings, otherwise it will damage the laser diode.
3. Semiconductor lasers are sensitive to temperature, working at high temperatures will reduce the photoelectric conversion efficiency and accelerate the aging of laser diode. It should be used under adequate heat dissipation or cooling conditions.
4. The laser should be used at the rated current and rated power, the output power is too high will accelerate the aging of laser diode.
5. Semiconductor lasers are electrostatic sensitive devices, anti-static measures should be taken during storage and transportation.
6. Lasers should be stored or work in a dry, ventilated environment to prevent damage to the laser from condensation.
7. The light emitting surface (cavity surface) is the key parts of the laser diode, any handling to damage the cavity surface should be strictly prohibited. It should be ensured that the laser diode is not contaminated, and damaged in mechanical.

